









	<h2 style="color: red;">NTP125N02RG</h2>
	<p>Hersteller-Teilenummer: NTP125N02RG</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 24V 15.9A TO220AB</p> <hr/> <p>Datenblätter:  NTP125N02RG.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 23501 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTP125N02RG
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 24V 15.9A TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23501 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	1.98W (Ta), 113.6W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	24V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	15.9A (Ta)
Rds On (Max) @ Id, Vgs	4.6 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	28nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	3440pF @ 20V
Verpackung	Tube



















































NTP125N02RG ist neu im Original, Suche NTP125N02RG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP125N02RG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP125N02RG: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTP13N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 13A TO220AB</p>	 <p>NTP18N06 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 15A TO220AB</p>	 <p>NTP1201A Sanken Electric Co., Ltd. NTP1201A SANKEN</p>	 <p>NTP125N02R AMI Semiconductor / ON Semiconductor NTP125N02R ON</p>
 <p>NTP1-7SH020 Cannon MICRO</p>	 <p>NTP18N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 15A TO220AB</p>	 <p>NTP13N10G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 13A TO220AB</p>	 <p>NTP1202A SANKEN NTP1202A SANKEN</p>

heiße Teile

Mehr

 NTP1201A	 NTP1202A	 NTP13N10	 NTP13N10G	 NTP18N06
 NTP18N06G	 NTP18N06L	 NTP18N06LG	 NTP22N06	 NTP22N06L
 NTP27N06G	 NTP27N06L	 NTP2955G	 NTP30N06L	 NTP30N06LG
 NTP30N20	 NTP30N20G	 NTP35N15	 NTP35N15G	 NTP4302G
 NTP45N06	 NTP45N06G	 NTP45N06L	 NTP45N06LG	 NTP477M04TDR
 NTP52N10	 NTP52N10G	 NTP5404N	 NTP5404NRG	 NTP5411NG
 NTP5412NG	 NTP5426N	 NTP5426NG	 NTP5860N	 NTP5860NG
 NTP5860NL	 NTP5860NLG	 NTP5862NG	 NTP5863N	 NTP5863NG
 NTP5864N	 NTP5864NG	 NTP60N06	 NTP60N06G	 NTP60N06L
 NTP60N06LG	 NTP6410AN	 NTP6410ANG	 NTP6411AN	 NTP6411ANG

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